

**(CRT TV HORIZONTAL DEFLECTION)
HIGH VOLTAGE DAMPER DIODE**
Table 1: Main Product Characteristics

$I_{F(AV)}$	6 A
V_{RRM}	1500 V
T_j	175°C
V_F (typ)	1.1 V
t_{rr} (typ)	150 ns
V_{FP} (typ)	26 V

FEATURES AND BENEFITS

- High breakdown voltage capability
- Specified turn on switching characteristics
- Very fast recovery diode
- Low static and peak forward voltage drop for low dissipation
- Insulated package (TO-220FPAC):
Insulating voltage = 2000V DC
Capacitance = 12 pF
- Planar technology allowing high quality and best electrical characteristics

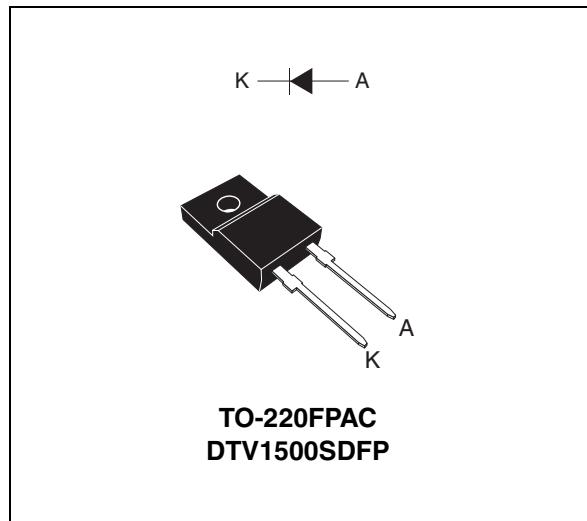
DESCRIPTION

High voltage diode especially designed for horizontal deflection stage in standard and high resolution displays for TV's.

This device is packaged in TO-220FPAC (insulated package).

Table 3: Absolute Maximum Ratings

Symbol	Parameter	Value	Unit
V_{RRM}	Repetitive peak reverse voltage	1500	V
$I_{F(RMS)}$	RMS forward voltage	15	A
I_{FSM}	Surge non repetitive forward current	50	A
T_{stg}	Storage temperature range	-65 to 175	°C
T_j	Maximum operating junction temperature	175	°C


Table 2: Order Code

Part Number	Marking
DTV1500SDFP	DTV1500SDFP

Figure 1: Conduction losses versus average current ($\delta=0.45$)

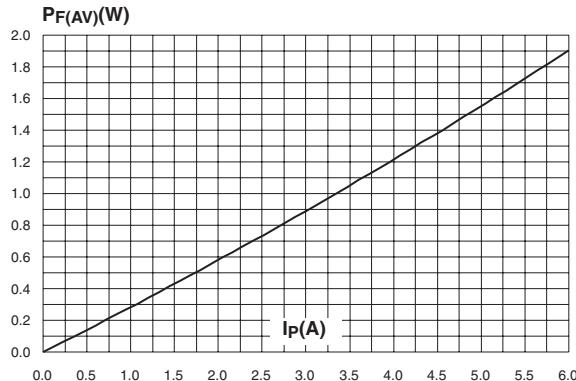


Figure 2: Forward voltage drop versus forward current

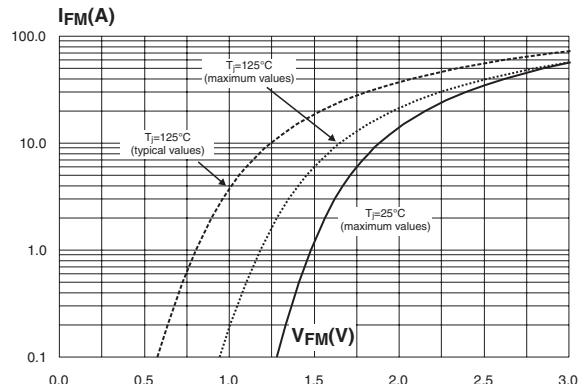


Figure 3: Reverse recovery charges versus dI_F/dt (typical values)

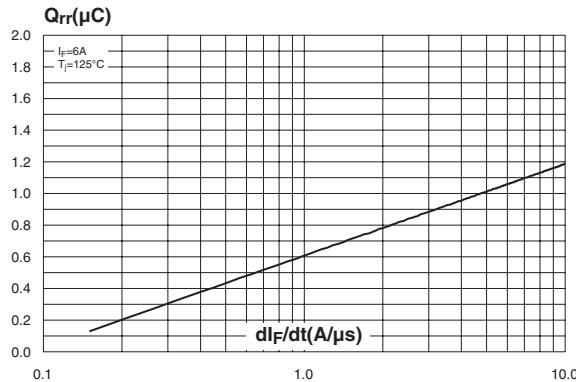


Figure 4: Peak reverse recovery current versus dI_F/dt (typical values)

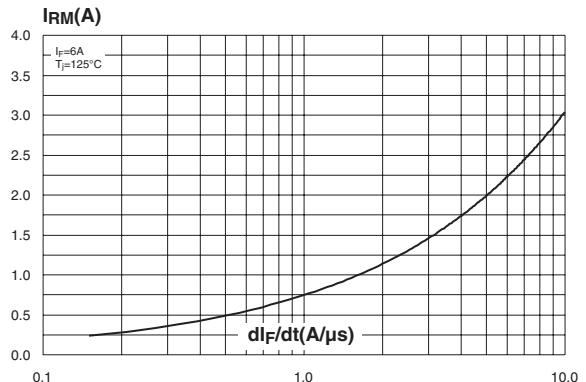


Figure 5: Transient peak forward voltage versus dI_F/dt (typical values)

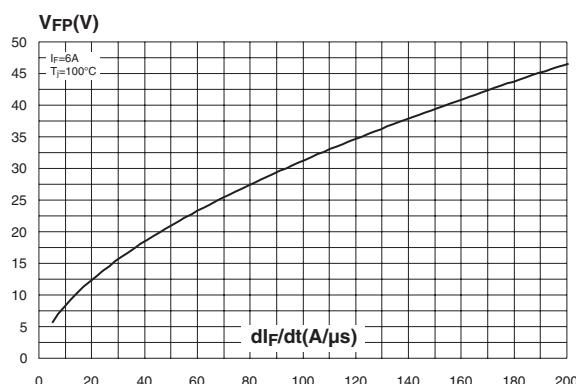


Figure 6: Forward recovery time versus dI_F/dt (typical values)

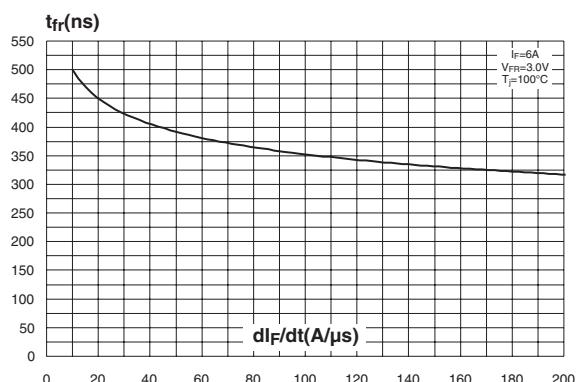


Figure 7: Relative variations of dynamic parameters versus junction temperature

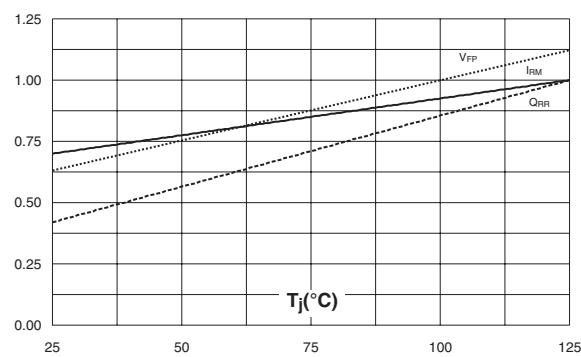


Figure 8: Junction capacitance versus reverse voltage applied (typical values)

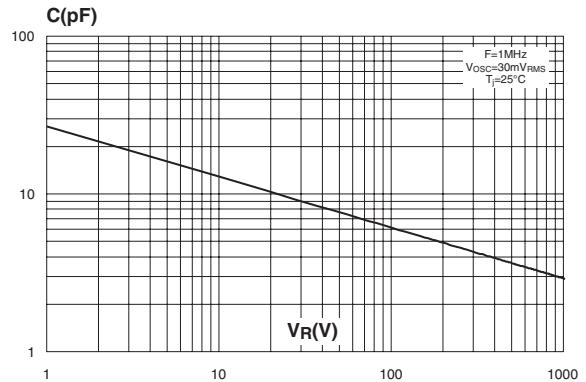


Figure 9: Relative variation of thermal impedance junction case versus pulse duration

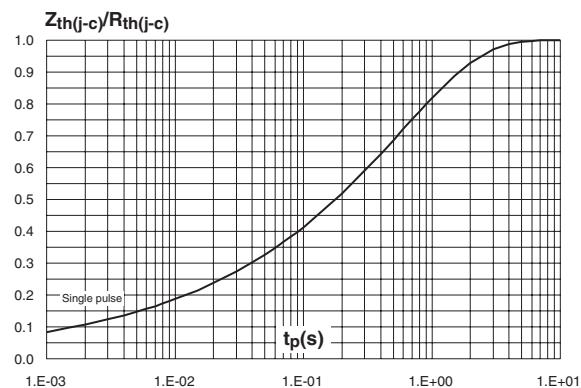


Figure 10: TO-220FPAC Package Mechanical Data

REF.	DIMENSIONS			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	4.4	4.6	0.173	0.181
B	2.5	2.7	0.098	0.106
D	2.5	2.75	0.098	0.108
E	0.45	0.70	0.017	0.027
F	0.75	1	0.030	0.039
F1	1.15	1.70	0.045	0.067
F2	1.15	1.70	0.045	0.067
G	4.95	5.20	0.195	0.204
G1	2.40	2.70	0.094	0.106
H	10	10.4	0.393	0.409
L2	16 Typ.		0.63 Typ.	
L3	28.6	30.6	1.126	1.204
L4	9.8	10.6	0.385	0.417
L6	15.9	16.4	0.626	0.645
L7	9.00	9.30	0.354	0.366
Dia.	3	3.20	0.118	0.126

Table 8: Ordering Information

Part Number	Marking	Package	Weight	Base qty	Delivery mode
DTV1500SDFP	DTV1500SDFP	TO-220FPAC	1.8 g	50	Tube

Table 9: Revision History

Date	Revision	Description of Changes
05-Jul-2004	1	First issue.
25-Nov-2004	2	Table 3 page 1: T_{stg} and T_j from upgraded from 150°C to 175°C.

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